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3mm Silicon PIN Photodiode

MODEL NO: PD202

Features:

- · Fast response time
- · High photo sensitivity
- · Small junction capacitance

Description:

PD202B is a high speed and high sensitive PIN photodiode in a standard 3Φ plastic package. The device is spectrally matched to infrared emitting diode.

Applications :

- · High speed photo detector
- Camera
- · Optoelectronic switch
- VCRs ,Video camera
- · Floppy disk drive

PART NO.	CHIP MATERIAL	LENS COLOR
PD	Silicon	Black

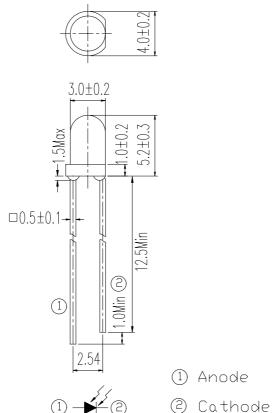


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Package Dimensions :



- Notes:
- 1.All dimensions are in millimeter.
- 2. Protruded resin under flange 1.5 mm Max.
- 3.Lead spacing is measured where the lead emerge from the package.
- 4.Lens color : Black.
- 5. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 6.These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
- 7.When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



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■ Absolute Maximum Ratings at T_A = 25°C

Parameter	Symbol	Rating	Unit	Notice
Reverse Voltage	V _R	32	V	
Power Dissipation	Pd	150	mW	
Lead Soldering Temperature	Tsol	260	$^{\circ}\!\mathbb{C}$	4mm from mold body less than 5 seconds
Operating Temperature	Topr	-25 ~ +85	$^{\circ}\!\mathbb{C}$	
Storage Temperature	Tstg	-40 ~ +85	$^{\circ}\!\mathbb{C}$	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Rang of Spectral Bandwidth	λ _{0.5}		840-1200		nm	
Wavelength of Peak Sensitivity	λ _P		980		nm	
Open-Circuit Voltage	Voc		0.42		V	Ee=5m W/c m²
Short-Circuit Current	Isc		15		μΑ	λp=940nm
Reverse Light Current	IL		15		μΑ	Ee=5m W/c m ² λ p=940nm V_R =5V
Dark Current	ld			10	nA	Ee=0m W/c m² V _R =10V
Reverse Breakdown Voltage	BV _R	32	170		V	Ee=0m W/c m² I _R =100µA
Total Capacitance	Ct		5		pF	Ee=0m W/c m² V _R =5V,f=1MHz
Rise/Fall Time	t _r /t _f		6/6		nS	$V_R=10V$ $R_L=1K\Omega$



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■ Typical Electrical/Optical/Characteristics Curves

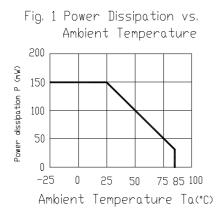


Fig.3 Dark Current vs. Ambient Temperature

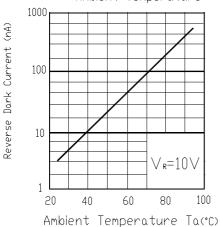
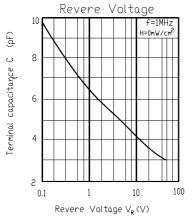


Fig.5 Terminal Capacitance vs.



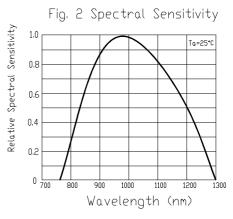


Fig.4 Reverse Light Current vs.Ee

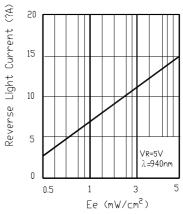
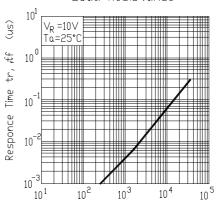


Fig.6 Responce Time vs. Load Resistance



Load Resistance RL(Ω)



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■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below. Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP: 260°C ±5 °C	5 secs	22 pcs		0/1
2	Temperature Cycle	H : +85°C 30 mins	50 cycles	22 pcs	I _L ≦Lx 0.8 L :Lower specification	0/1
		L : -55°C 30 mins			limit	
3	Thermal Shock	H: +100°C 5 mins ↑ 10 secs	50 cycles	22 pcs		0/1
		L : -10°C 5 mins				
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 pcs		0/1
5	Low Temperature Storage	TEMP. : -55°℃	1000 hrs	22 pcs		0/1
6	DC Operating Life	$V_R=5V$	1000 hrs	22 pcs		0/1
7	High Temperature / High Humidity	85℃ / 85% R.H.	1000 hrs	22 pcs		0/1



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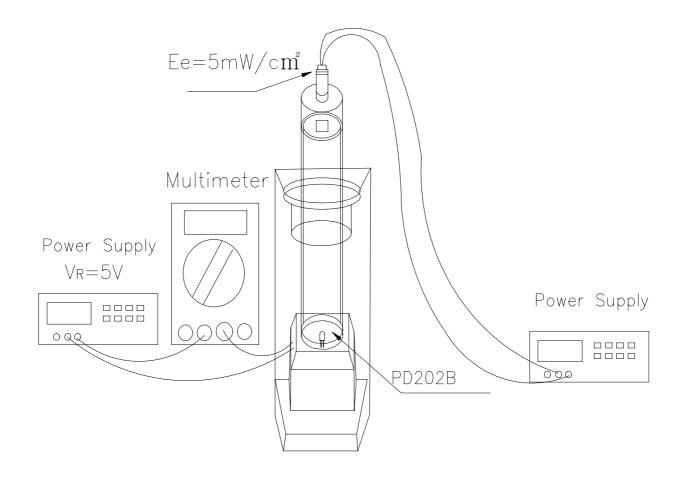
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■ Test Method For Reverse Light Current

Condition: Ee=5mW/cm², V_R=5V Test Item: Reverse Light Current

Unit : μ A



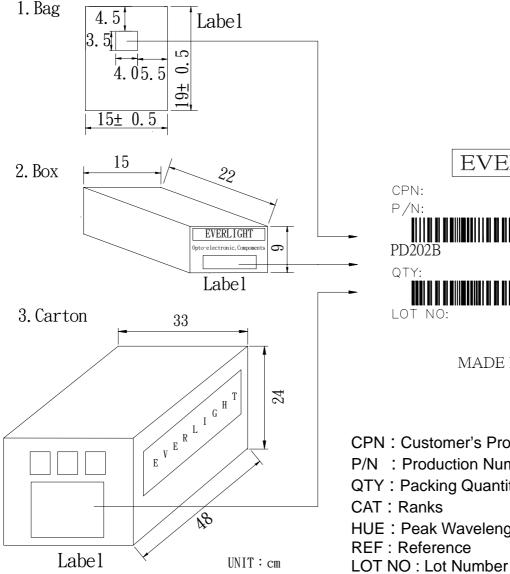


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Packing Specifications



EVERLIGHT

HUE:

MADE IN TAIWAN

CPN: Customer's Production Number

P/N: Production Number QTY: Packing Quantity

HUE: Peak Wavelength

MADE IN TAIWAN: Production place

■ Packing Quantity Specification

- 1. 1000 Pcs/1Bag , 4 Bags/1Box
- 2. 10 Boxes/1Carton